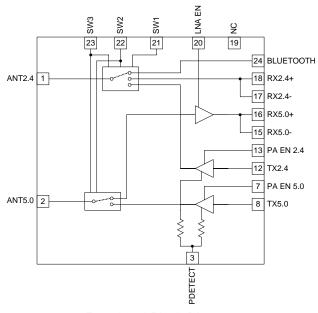
Package Style: QFN, 24-Pin, 4mmx4mm

### **Features**

- Single-Module Radio Front-End
- Single Supply Voltage 3.15V to 4.5V
- Integrated 2.5 GHz & 5 GHZ PA's, RX Baluns, Filters & Switches for TX & RX, and High Band LNA
- P<sub>OUT</sub>=16dBm, 11g, OFDM<3.3% EVM</li>
   P<sub>OUT</sub>=16dBm, 11a, OFDM<3.3% EVM</li>

## **Applications**

- IEEE802.11a/b/g WLAN Applications
- Single-Chip RF Front-End Module
- 2.5 GHz and 5 GHz ISM Bands Applications
- Wireless LAN Systems
- Portable Battery-Powered Equipment



Functional Block Diagram

# **Product Description**

The RF3388 is a single-chip dual-band integrated front-end module (FEM) for high-performance WLAN applications in the 2.5 GHz and 5 GHz ISM bands. The RF3388 addresses the need for aggressive size reduction for a typical 802.11a/b/g RF front-end design and greatly reduces the number of components outside of the core chipset thus minimizing the footprint and assembly cost of the overall 802.11a/b/g solution. The RF3388 contains integrated PA's for 2.5 GHz and 5 GHz, TX/RX switch for each band, LNA for the 5.0 GHz receive band, baluns for both low and high receive bands, some bypass capacitors, built-in power detector for both bands, and some filtering for transmit and receive paths. The RF3388 is packaged in a 24-pin, 4mmx4mm QFN package with backside ground. The RF3388 greatly minimizes next level board space and allows for simplified integration.

#### **Ordering Information**

RF3388 3.7 V, Dual-Band Front-End Module RF3388PCBA-410 Fully Assembled Evaluation Board

# Optimum Technology Matching® Applied

☐ GaAs HBT	☐ SiGe BiCMOS	<b></b> GaAs pHEMT	☐ GaN HEMT
☐ GaAs MESFET ✓ InGaP HBT	☐ Si BiCMOS	☐ Si CMOS	
<b>▼</b> InGaP HBT	☐ SiGe HBT	☐ Si BJT	



Please contact RFMD Technical Support at (336) 678-5570 for more information.